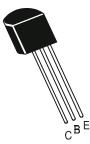


## PNP SILICON PLANAR EPITAXIAL TRANSISTORS



BC559, B, C BC560, B, C

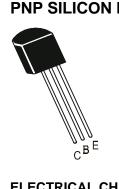
TO-92 Plastic Package

## Low Noise Transistors

ABSOLUTE MAXIMUM RATINGS(	Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BC559	BC560	UNITS
Collector Emitter Voltage	V <sub>CEO</sub>	30	45	V
Collector Base Voltage	V <sub>CBO</sub>	30	50	V
Emitter Base Voltage	V <sub>EBO</sub>	5	5	V
Collector Current Continuous	I <sub>C</sub>	10	00	mA
Power Dissipation @ Tc=25°C	P <sub>D</sub>	62	25	mW
Derate Above 25°C		5	5	mW/⁰C
Power Dissipation @ Tc=25°C	P <sub>D</sub>	1.	5	W
Derate Above 25°C		1	2	mW/⁰C
Operating And Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	-55 to	+150	°C
THERMAL RESISTANCE				
Junction to ambient	R <sub>th(j-a)</sub>	20	00	°C/W
Junction to case	R <sub>th(j-c)</sub>	83	.3	°C/W

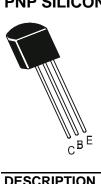
# PNP SILICON PLANAR EPITAXIAL TRANSISTORS



TO-92 Plastic Package

ELECTRICAL CHARACTERISTICS (Ta=25°C Unless Specified Otherwise)							
DESCRIPTION		SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Voltage							
	BC559	$V_{CEO}$	I <sub>C</sub> =10mA,I <sub>B</sub> =0	30			V
	BC560			45			V
Collector Base Voltage		.,					
	BC559	V <sub>CBO</sub>	$I_{C}=10\mu A, I_{E}=0$	30			V
	BC560			50			V
Emitter Base Voltage		V <sub>EBO</sub>	I <sub>E</sub> =10μΑ, I <sub>C</sub> =0	5			V
		200		-			
Collector Cut off Current		I <sub>CBO</sub>	$V_{CB}$ =30V, $I_{E}$ = 0			15	nA
			$V_{CB} = 30V, I_{F} = 0$			5	μA
			Ta= +125°C			•	P** 1
Emitter Cut off Current		I <sub>EBO</sub>	V <sub>CE</sub> =40V, I <sub>C</sub> =0			15	nA
DC Current Gain							
	В		V <sub>CE</sub> =5V,I <sub>C</sub> =10uA	100			
	С			100			
	_			400		100	
	В		V <sub>CE</sub> =5V,I <sub>C</sub> =2mA	180		460	
	С			380		800	
BC55	9, BC560			120		800	
Collector Emitter Saturation \	/oltage						
		V <sub>CE(sat)</sub>	I <sub>C</sub> =10mA,I <sub>B</sub> =0.5mA			0.25	V
		. ,	I <sub>C</sub> =100mA,I <sub>B</sub> =see note 1			0.6	V
			I <sub>C</sub> =100mA,I <sub>B</sub> =5mA*		0.25		V
			· · · ·				-

# PNP SILICON PLANAR EPITAXIAL TRANSISTORS



TO-92 Plastic Package

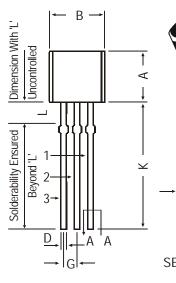
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Base Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =100mA,I <sub>B</sub> =5mA*		1.1		V
Base Emitter On Voltage	$V_{BE(on)}$	$I_{C}$ =10uA, $V_{CE}$ =5V $I_{C}$ =100uA, $V_{CE}$ =5V		0.52 0.55		V V
		$I_{C}=2mA, V_{CE}=5V$	0.55		0.70	V

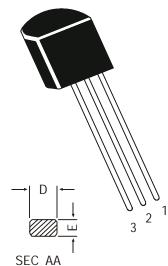
#### ELECTRICAL CHARACTERISTICS (Ta=25°C Unless Otherwise Specified)

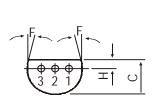
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
DYNAMICS CHARACTERISTICS						
Transition Frequency	f⊤	I <sub>C</sub> =10mA, V <sub>CE</sub> =5V				
		f=100MHz		250		MHz
Collector Base Capacitance	$C_{cbo}$	$V_{CB} = 10V, I_E = 0,$ f = 1MHz		2.5		pF
Noise Figure	$NF_1$	V <sub>CE</sub> =5V,I <sub>C</sub> =200uA R <sub>S</sub> =2KW,f=30H <sub>Z</sub> To 15KHz			2.0	dB
	NF <sub>2</sub>	$V_{CE} = 5V,I_C = 200uA$ $R_S = 100KW,f = 1.0KH_Z$ f = 200HZ			10	dB
Small Signal Current Gain						
	B   h <sub>fe</sub>	V <sub>CE</sub> =5V,I <sub>C</sub> =2mA	240		500	
	С	f=1kHz	450		900	

## **TO-92 Plastic Package**

#### **TO-92 Plastic Package**







#### **PIN CONFIGURATION**

1. EMITTER

2. BASE

3. COLLECTOR

DIM	MIN.	MAX.		
А	4.32	5.33		
В	4.45	5.20		
С	3.18	4.19		
D	0.41	0.55		
E	0.35 0.50			
F	5 DI	EG		
G	1.14	1.40		
Н	1.14	1.53		
Κ	12.70	_		
L	1.982	2.082		

All diminsions in mm.

Ammo Pack

**TO-92 Transistors on Tape and Ammo Pack** 

#### All dimensions in mm unless specified otherwise

ITEM		SPECIFICATION				DEMARKA
TIEM	SYMBOL	MIN.	NOM.	MAX.	TOL .	REMARKS
BODY WIDTH	A1	4.0		4.8		
BODY HEIGHT	A	4.8		5.2 4.2		
BODY THICKNESS PITCH OF COMPONENT	T P	3.9	12.7	4.Z	±1	
FFFD HOLF PITCH	Po		12.7		+0.3	CUMULATIVE PITCH
					_0.0	ERROR 1.0 mm/20
FEED HOLE CENTRE TO						PITCH
COMPONENT CENTRE	P2		6.35		±0.4	TO BE MEASURED AT
					0.(	BOTTOM OF CLINCH
DISTANCE BETWEEN OUTER	F		5.08		+0.6 -0.2	
COMPONENT ALIGNMENT	∆h		0	1	0.2	AT TOP OF BODY
TAPE WIDTH	W		18		±0.5	
HOLD-DOWN TAPE WIDTH	Wo		6		±0.2	
HOLE POSITION	W1		9		+0.7 -0.5	
HOLD-DOWN TAPE POSITION	W2		0.5		+0.2	
LEAD WIRE CLINCH HEIGHT	Ho		16		$\pm 0.2$	
COMPONENT HEIGHT	H1			23.25		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER TOTAL TAPE THICKNESS	Do t		4	1.2	±0.2	t1 0.3 - 0.6
LEAD - TO - LEAD DISTANCEF1,	F2		2.54	1.2	+0.4	11 0.3 - 0.0
			2.01		-0.1	
CLINCH HEIGHT	H2			3		
PULL - OUT FORCE	(P)	6N				

NOTES

MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20

 MOVANION TO CONSELECT E ANALYSIC E CONSELECT E CONSEL A DOLDOUWN HAPE NOT TO EXCEED BETOND THE EDGE(3) OF CARRIER HAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.
NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

BC559, B, C BC560, B, C

TO-92 Plastic Package

#### Disclaimer

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